

# Data Sheet Supplement Version 3.0 (valid for 8" product)

# Dynamic Differential Hall Effect Sensor TLE4926C-HT E6747

For all parameters not specified in this document the TLE4925C data sheet is valid.



Туре	Marking	Ordering Code	Package
TLE4926C-HT E6747	26C8A	SP000269345	PG-SSO-3-9



## 1Package

• 47nF capacitor<sup>1</sup> between V<sub>S</sub> and GND needed for micro cuts in power suply using existing P-SSO-3-9 package.

### 2 Absolute Maximum Ratings

Parameter	Symbol	min.	typ.	max.	Unit	Conditions
Junction	Tj	-40			°C	-
temperature				155	°C	5000 h (not additive)
				165	°C	2500 h (not additive)
				175	°C	500 h (not additive)
				195	°C	10x1 h (additive to the other life times).

### 3 Operating Range

Parameter	Symbol	min.	typ.	max.	Unit	Conditions
Operating junction	Tj	-40			°C	-
temperature				155	°C	5000 h (not additive)
				165	°C	2500 h (not additive)
				175	°C	500 h (not additive)
						reduced signal
						quality permittable
						(e.g. jitter).

<sup>&</sup>lt;sup>1</sup> value of capacitor: 47nF±10%; (excluded drift due to temperature and over lifetime); ceramic: X7R; maximum voltage: 50V.



#### 4 Electro Magnetic Compatibility – (values depend on R<sub>Series</sub>)

Ref. ISO 7637-2; see test circuit of figure 15;

 $\Delta B_{PP}$  = 10mT (ideal sinusoidal signal); V<sub>S</sub>=13.5V ± 0.5V, f<sub>B</sub>= 1000Hz; T= 25°C; R<sub>Series</sub> ≥ 200 $\Omega$ ;

No.	Parameter	Symbol	Level/typ	Status
1.2.1	Testpulse 1	V <sub>EMC</sub>	III / -90V	С
	Testpulse 2		III / 40V	A <sup>1</sup>
	Testpulse 3a		IV / -150V	А
	Testpulse 3b		IV / 100V	А
	Testpulse 4		IV / -7V	А
	Testpulse 5		III / 66.5V	С

Note: Test criteria for status A: No missing pulse no additional pulse on the IC output signal plus duty cycle and jitter are in the specification limits. Test criteria for status B: No missing pulse no additional pulse on the IC output signal. (Output

signal "OFF" means switching to the voltage of the pull-up resistor). Test criteria for status C: One or more parameter can be out of specification during the exposure but returns automatically to normal operation after exposure is removed. Test criteria for status E: IC destroyed.

#### Ref. ISO 7637-3; TP 1 and TP 2 ref. DIN 40839-3; see test circuit of figure 15;

No.	Parameter	Symbol	Level/typ	Status
1.2.2	Testpulse 1	V <sub>EMC</sub>	IV / -30V	А
	Testpulse 2		IV / 30V	А
	Testpulse 3a		IV / -60V	А
	Testpulse 3b		IV / 40V	А

Ref. ISO 11452-3; see test circuit of figure 15; measured in TEM-cell

 ∆B <sub>PP</sub> =	4mT (ideal sinusoidal s	ignal); $V_{\rm S}$ =13.5V ± 0,5V,	f <sub>B</sub> = 200Hz; T= 25°C; R <sub>5</sub>	$_{\text{Series}} \ge 200\Omega;$

No.	Parameter	Symbol	Level/max	Remarks
1.2.3	EMC field strength	E <sub>TEM-Cell</sub>	IV / 200V/m	AM=80%, f=1kHz;

Note: Stresses above those listed here may cause permanent damage to the device. Exposure to absolute maximum rating conditions for extended periods may affect device reliability. Test condition for the trigger window:  $f_{B-field}$ =200Hz,  $B_{pp}$ =4mT, vertical limits are  $\pm$ 200mV and horizontal limits are  $\pm$ 200µs.

<sup>&</sup>lt;sup>1</sup> Valid for general function, current consumption and jitter may be out of spec during test pulse 2.



Revisio	n History:	April 2007	Version 3.0
Previous \	/ersion: 2.0		
Page	Subjects (ma	jor changes since last re	evision)
1	Data sheet is	valid for 8" products	
1	Ordering cod	e added	
3	EMC perform	ance conducted pulses	ISO7637-1 TP1 and TP5 updated

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